Taiwan Semiconductor

2A, 200V - 600V Super Fast Surface Mount Rectifier

FEATURES

TAIWAN

• Glass passivated chip junction

EMICONDUCTOR

- Ideal for automated placement
- Super fast recovery time for high efficiency
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free

APPLICATIONS

- DC to DC converter
- Switching mode converters and inverters
- Freewheeling application

MECHANICAL DATA

- Case: DO-214AA (SMB)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Polarity: Indicated by cathode band
- Weight: 0.090g (approximately)

KEY PARAMETERS				
PARAMETER	VALUE	UNIT		
l _F	2	А		
Vrrm	200 - 600	V		
IFSM	50	А		
Тј мах	150	°C		
Package	DO-214AA (SMB)			
Configuration	Single die			





DO-214AA (SMB)



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)					
PARAMETER	SYMBOL	ES2D-T	ES2G-T	ES2J-T	UNIT
Marking code on the device		ES2D	ES2G	ES2J	
Repetitive peak reverse voltage	Vrrm	200	400	600	V
Reverse voltage, total rms value	Vrms	140	280	420	V
Forward current	lF	2			Α
Surge peak forward current 8.3ms single half sine-wave superimposed on rated load	IFSM	50		А	
Junction temperature	TJ	- 55 to +150		°C	
Storage temperature	T _{STG}	- 55 to +150		°C	



THERMAL PERFORMANCE					
PARAMETER	SYMBOL	ТҮР	UNIT		
Junction-to-lead thermal resistance	$R_{\Theta JL}$	20	°C/W		
Junction-to-ambient thermal resistance	Reja	75	°C/W		

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
Forward voltage ⁽¹⁾	ES2D-T	I⊧ = 2A, TJ = 25°C	VF	-	0.95	V
	ES2G-T			-	1.30	V
	ES2J-T			-	1.70	V
Reverse current @ rated V _R ⁽²⁾		T _J = 25°C	IR	-	10	μA
		T _J = 125°C		-	350	μA
Junction capacitance	ES2D-T	1MHz, V _R = 4.0V	CJ	25	-	pF
	ES2G-T			20	-	pF
	ES2J-T					
Reverse recovery time		$I_F = 0.5A, I_R = 1.0A$ $I_{rr} = 0.25A$	t _{rr}	-	35	ns

Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

ORDERING INFORMATION				
ORDERING CODE ⁽¹⁾	PACKAGE	PACKING		
ES2x-T	DO-214AA (SMB)	3,000 / Tape & Reel		

Notes:

1. "x" defines voltage from 200V(ES2D-T) to 600V(ES2J-T)



CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

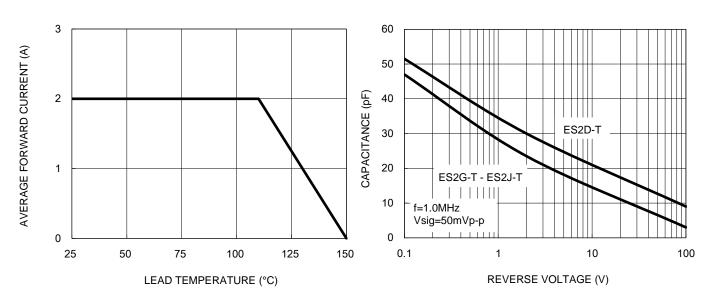
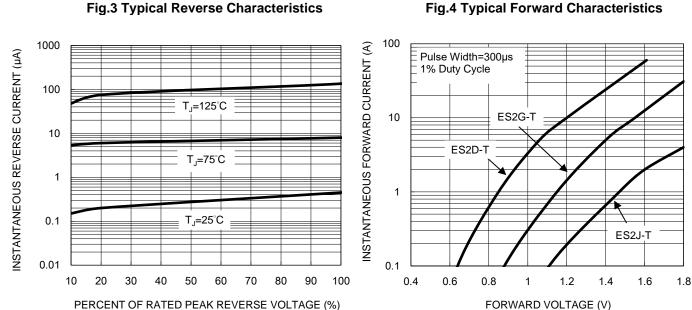


Fig.1 Forward Current Derating Curve

Fig.2 Typical Junction Capacitance





CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

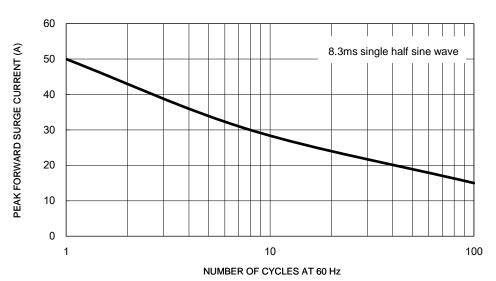
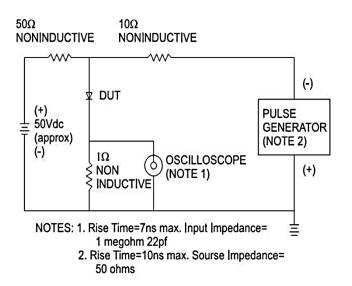
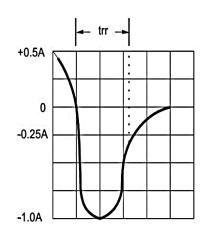


Fig.5 Maximum Non-Repetitive Forward Surge Current

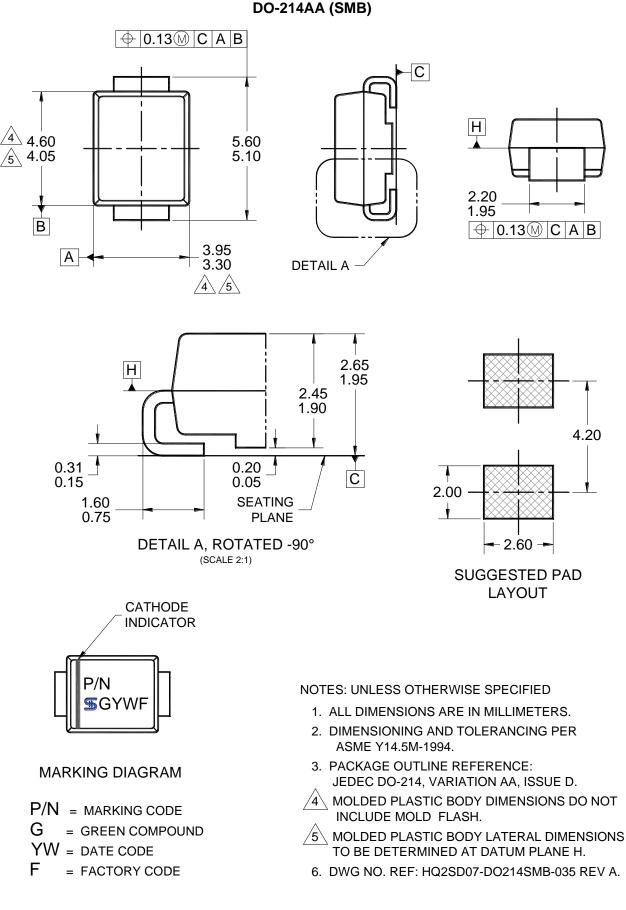








PACKAGE OUTLINE DIMENSIONS



Version: D2305



Taiwan Semiconductor

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